## 1 SS315 SILICON EPITAXIAL SCHOTTKY BARRIER DIODE

## Applications

- UHF Band Mixer

PINNING

| PIN | DESCRIPTION |
| :---: | :--- |
| 1 | Cathode |
| 2 | Anode |



Top View
Marking Code: "ST"
Simplified outline SOD-323 and symbol

Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{a}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Peak Reverse Voltage | $\mathrm{V}_{\mathrm{RM}}$ | 5 | V |
| Forward Current | $\mathrm{I}_{\mathrm{F}}$ | 30 | mA |
| Junction Temperature | $\mathrm{T}_{J}$ | 125 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {stg }}$ | -55 to +125 | ${ }^{\circ} \mathrm{C}$ |

Electrical Characteristics at $\mathrm{T}_{\mathrm{a}}=25 \mathrm{C}$

| Parameter | Symbol | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Forward Current <br> at $\mathrm{V}_{\mathrm{F}}=0.5 \mathrm{~V}$ | $\mathrm{I}_{\mathrm{F}}$ | 30 | - | - | mA |
| Reverse Current <br> at $\mathrm{V}_{\mathrm{R}}=0.5 \mathrm{~V}$ | $\mathrm{I}_{\mathrm{R}}$ | - | - | 25 | $\mu \mathrm{~A}$ |
| Total Capacitance <br> at $\mathrm{V}_{\mathrm{R}}=0.2 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ | $\mathrm{C}_{\mathrm{T}}$ | - | 0.6 | - | pF |

## Typical Characteristics





## PACKAGE OUTLINE



